

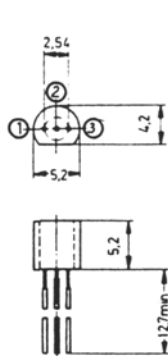
2N 5462
Silicon P-Channel JFET

Text: Uni, ra
Similar: =2N5460
Case: D9/c
Prod.:

Isi: Harris Semiconductor
Mot: Motorola GmbH
Nsc: National Semiconductor GmbH
Phi: Philips Semiconductor
Sol: Solitron Devices, Inc.
Val: Valvo (Philips Semiconductor)
Six: Siliconix GmbH (Temic Telefunken microelectronic GmbH)

UDG: -40V
UDS: 40V
UGS: 40V
IG: -10mA
Ptot: 0,31W@Tu: 25°C
RthU: 355°C/W
Tj: 135°C

Idss min: -4mA@UDS: -15V
Idss max: -16mA@UDS: -15V
UPmin: 1,8V@UDS: -15V ID: -1µA
UGSmin: 1,5V@UDS: -15V ID: -400µA
UPmax: 9V@UDS: -15V ID: -1µA
UGSmax: 6V@UDS: -15V ID: -400µA
|Yfs| min: 2mS@UDS: -15V
|Yfs| max: 6mS@UDS: -15V
|Yos| max: 0,075mS@UDS: -15V
|Yfs| max: 1mS@UDS: -15V
F: <2,5dB@UDS: -15V
IGSS: 5nA@UGS: 20V



Pin1: Gate
Pin2: Drain
Pin3: Source